

CEN-U95
PNP SILICON
DARLINGTON TRANSISTOR



TO-202 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CEN-U95 is a PNP Silicon Darlington Transistor designed for general purpose amplifier and driver applications where high gain and high power dissipation is required.

MARKING: FULL PART NUMBER

APPLICATIONS:

- Designed for general purpose amplifiers and drivers

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage	
Collector-Emitter Voltage	
Emitter-Base Voltage	
Continuous Collector Current	
Power Dissipation	
Power Dissipation ($T_C=25^\circ\text{C}$)	
Operating and Storage Junction Temperature	
Thermal Resistance	
Thermal Resistance	

FEATURES:

- High Collector Current (2.0A)
- High DC Current Gain (25K MIN)

SYMBOL		UNITS
V_{CBO}	50	V
V_{CES}	40	V
V_{EBO}	10	V
I_C	2.0	A
P_D	1.0	W
P_D	10	W
T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
θ_{JA}	125	$^\circ\text{C/W}$
θ_{JC}	12.5	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

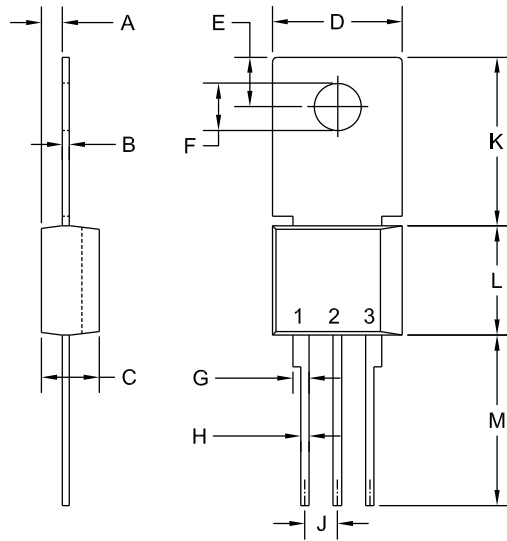
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=30\text{V}$		100	nA
I_{EBO}	$V_{EB}=8.0\text{V}$		100	nA
BV_{CBO}	$I_C=100\mu\text{A}$	50		V
BV_{CES}	$I_C=100\mu\text{A}$	40		V
BV_{EBO}	$I_E=10\mu\text{A}$	10		V
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=2.0\text{mA}$		1.5	V
$V_{BE(SAT)}$	$I_C=1.0\text{A}, I_B=2.0\text{mA}$		2.0	V
$V_{BE(ON)}$	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$		2.0	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=200\text{mA}$	25K	150K	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=500\text{mA}$	15K		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$	4K		
f_T	$V_{CE}=5.0\text{V}, I_C=200\text{mA}, f=100\text{MHz}$	50		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		12	pF

R0 (12-October 2011)

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TO-202 CASE - MECHANICAL OUTLINE



R1

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:

FULL PART NUMBER

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.071	1.40	1.80
B	0.016	0.024	0.40	0.60
C	0.173	0.181	4.40	4.60
D	0.374	0.413	9.50	10.50
E	0.146	0.154	3.70	3.90
F (DIA)	0.142	0.150	3.60	3.80
G	0.039	0.055	1.00	1.40
H	0.024	0.031	0.60	0.80
J	0.094	0.106	2.39	2.69
K	0.492	0.551	12.50	14.00
L	0.327	0.346	8.30	8.80
M	0.492	0.531	12.50	13.50

TO-202 (REV: R1)

R0 (12-October 2011)